

All Products / Testing and Detection / Detectors

Segmented InGaAs Photodiodes



- Four Individual Active Area Elements
- High Response Uniformity and Low Crosstalk
- Ideal for Position Detection and Beam Alignment
- <u>Segmented Silicon Photodiodes</u> and <u>InGaAs Photodiodes</u> Also Available

Common Specifications

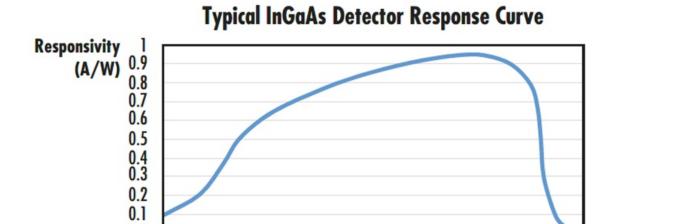
Physical & Mechanical Properties

Element Gap (mm):	0.045
Electrical	
Responsivity @ 1310nm (A/W):	0.85 minimum / 0.9 typical
Responsivity @ 1550nm (A/W):	0.9 minimum / 0.95 typical
Environmental & Durability Factors	;
Operating Temperature (°C):	-40 to +75
Storage Temperature (°C):	-55 to +125

Technical Information

800

900



1000 1100 1200 1300 1400 1500 1600 1700 1800 λ (nm)

Products

Size of Active Area (mm)	Connector	Stock Number	Price	Buy
1 Dia.	TO-5	<u>#17-077</u>	S\$421.40 Volume Pricing	2 In Stock
3 Dia.	TO-8	<u>#17-078</u>	S\$861.00 Volume Pricing	Contact Us



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